imall

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200mW, PNP Small Signal Transistor

FEATURES

- Epitaxial planar die construction
- Surface device type mounting
- Moisture sensitivity level 1
- Matte Tin(Sn) lead finish with Nickel(Ni) underplate
- Pb free and RoHS compliant
- Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

MECHANICAL DATA

- Case : SOT- 23 small outline plastic package
 Terminal : Matte tin plated, lead free, solderable per MIL-STD-202, method 208 guaranteed
- High temperature soldering guaranteed : 260°C/10s
- Weight : 0.008 grams (approximately)









<u>SOT-23</u>

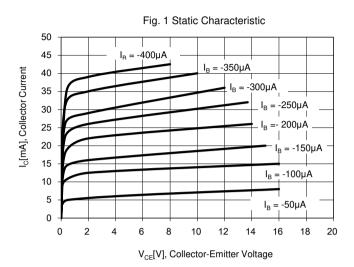
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)				
PARAMETE	R	SYMBOL	VALUE	UNIT
Power Dissipation		PD	200	mW
	BC856		-80	
Collector-Base Voltage	BC857	V _{CBO}	-50	V
	BC858		-30	
	BC856		-65	
Collector-Emitter Voltage	BC857	V _{CEO}	-45	V
	BC858		-30	
Emitter-Base Voltage		V _{EBO}	-5	V
Collector Current		Ι _C	-0.1	A
Junction and Storage Temperature Range		T_J,T_STG	-55 to + 150	°C

	PARAMETER			SYMBOL	MIN	MAX	UNIT
	BC856				-80	-	
Collector-Base Breakd Voltage	BC857	Ι _C = -10μΑ	$I_E = 0$	V _{(BR)CBO}	-50	-	V
Voltage	BC858				-30	-	
	. BC856				-65	-	
Collector-Emitter Breal Voltage	down BC857	I _C = -10mA	$I_B = 0$	V _{(BR)CEO}	-45	-	V
Voltage	BC858				-30	-	
Emitter-Base Breakdov	vn Voltage	Ι _Ε = -1μΑ	$I_{C}=0$	V _{(BR)EBO}	-5	-	V
	BC856	V_{CB} = -70V			-	-100	
Collector Cut-off Curre	nt BC857	V_{CB} = -45V	$I_E = 0$	I _{CBO}	-	-100	nA
	BC858	V_{CB} = -25V			-	-100	
Emitter Cut-off Current		$V_{EB} = -5V$	I _C =0	I _{EBO}	-	-0.1	μA
	BC856A, BC857A, BC858A				125	250	
DC Current Gain	BC856B, BC857B, BC858B	$V_{CE} = -5V$	I _C = -2mA	h _{FE}	220	475	
	BC857C, BC858C				420	800	
Collector-Emitter Satur	ation Voltage	I _C = -100mA	I _B = -5mA	V _{CE(sat)}	-	-0.65	V
Base-Emitter Saturatio	n Voltage	I _C = -100mA	I _B = -5mA	V _{BE(sat)}	-	-1.1	V
Transition Frequency	V_{CE} = -5V	I _C = -10mA	f= 100MHz		100	-	MHz



RATINGS AND CHARACTERISTIC CURVES

(TA=25°C unless otherwise noted)



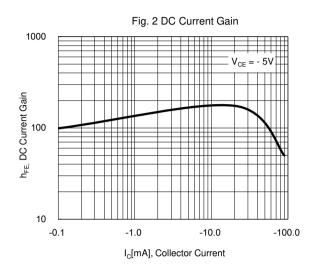


Fig.3 Base-Emitter Saturation Voltage VS.Collector-Emitter Saturation

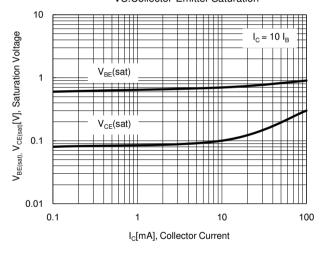
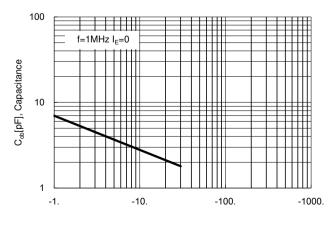


Fig.5 Collector Output Capacitance



V_{CB}[V], Collector-Base Voltage

Fig. 4 Base-Emitter On Voltage

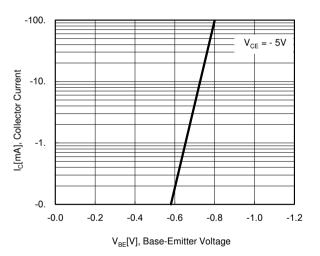
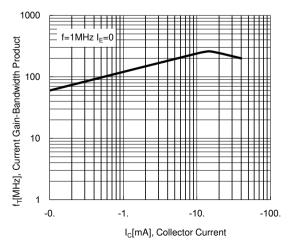


Fig. 6 Current Gain Bandwidth Product





RATINGS AND CHARACTERISTIC CURVES

(TA=25°C unless otherwise noted)

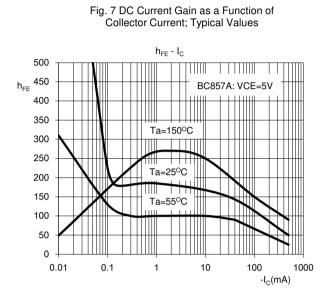
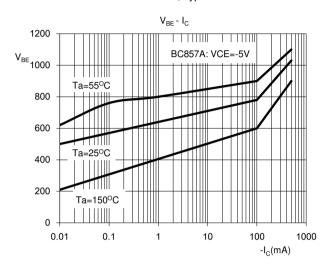


Fig. 8 Base-Emitter Voltage as a Function of Collector Current; Typical Values





Ordering informat	tion			
Part No.	Packing code	Packing code suffix(*)	Package	Packing
BC85xx (Note 1)	RF	G	SOT-23	3K / 7 " Reel

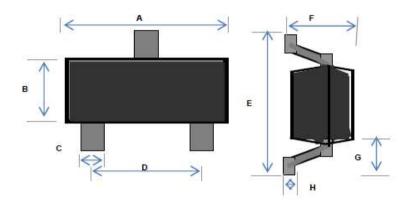
Note 1 : "xx" is Device Code from "6A" thru "8C".

*: optional available

Example				
Preferred Part No.	Part No.	Packing code	Packing code suffix	Description
BC856A RFG	BC856A	RF	G	Green compound

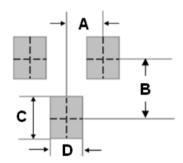


Dimensions



DIM.	Unit(mm)		Unit(inch)	
DIW.	Min	Max	Min	Max
А	2.70	3.10	0.106	0.122
В	1.10	1.50	0.043	0.059
С	0.30	0.51	0.012	0.020
D	1.78	2.04	0.070	0.080
Е	2.20	2.60	0.087	0.102
F	0.90	1.30	0.035	0.051
G	0.550 REF		0.022	REF
Н	0.1 REF		0.004	REF

Suggested PAD Layout



DIM.	Unit(mm)	Unit(inch)	
DIM.	Тур.	Тур.	
А	0.95	0.037	
В	2.0	0.079	
С	0.9	0.035	
D	0.8	0.031	

Marking

Part No.	Marking
BC856A	ЗA
BC856B	3B
BC857A	3E
BC857B	3F
BC857C	3G
BC858A	3J
BC858B	3K
BC858C	3L



Taiwan Semiconductor

Small Signal Product

Version : H1606

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